

## On-board Memory Unit

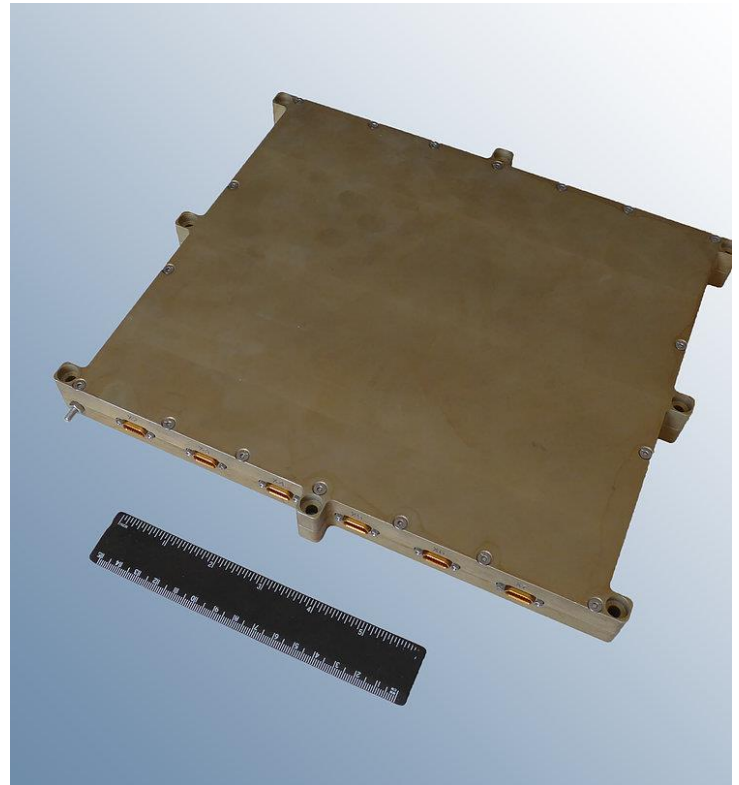
The On-board Memory Unit is designed to provide data storage for the remote sensing satellites payloads.

### Applications

- Small satellites on-board data handling subsystems
- Autonomous storage for the secondary payloads of the large spacecraft

### Features

- Large capacity and high write/read rate
- File system with file/block write, transmit, selective re-transmit and erase
- NAND flash wear control and ECC
- Mux'es up to four data streams
- Directly interfaces with SAIT high-throughput transmitters
- Two units stack up to provide double redundancy with cross-strapped connections to data sources and transmitters



### Specifications

Storage capacity			128 GB Option 512 GB
Sustained write throughput			2.2 Gbps
Read throughput			2.2 Gbps
Error rate (3 days storage time on LEO)			$10^{-12}$
Power consumption write			12 W
read			12 W
standby			0W
Power supply			27 V (22-35 V)
Weight	1.8 kg	Size	292x264x27 mm
Operating temperature			-20 °C to +50 °C
Survival temperature			-50 °C to +70 °C
MTBF	400k hours	Design life	7 years
Radiation at the component level			>6 krad (average enclosure shielding 1.5 g/cm <sup>2</sup> )
SEL tolerance			>40 MeV·cm <sup>2</sup> /mg
Data interface			LVDS. Four ports with 4 pairs each (primary data/clock, redundant data/clock, spare). Customizable.
Control and telemetry interface			MIL-STD-1553 or CAN-2B (dual redundant buses) Two RS-422 for external devices control

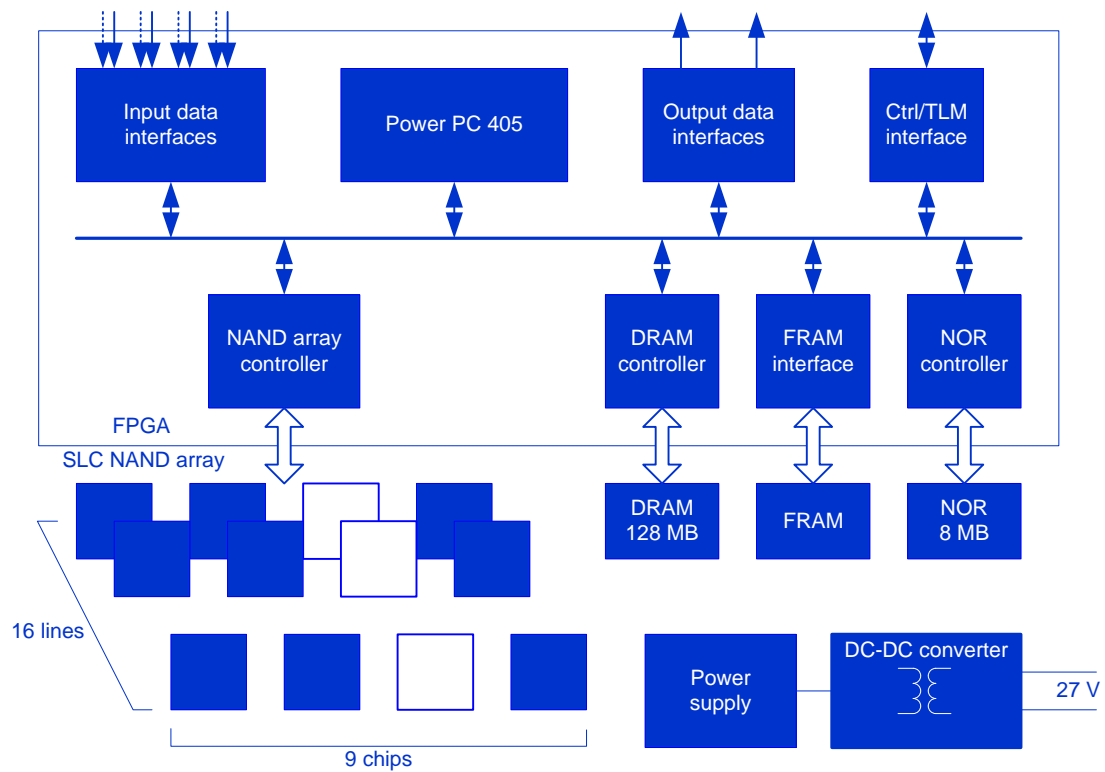
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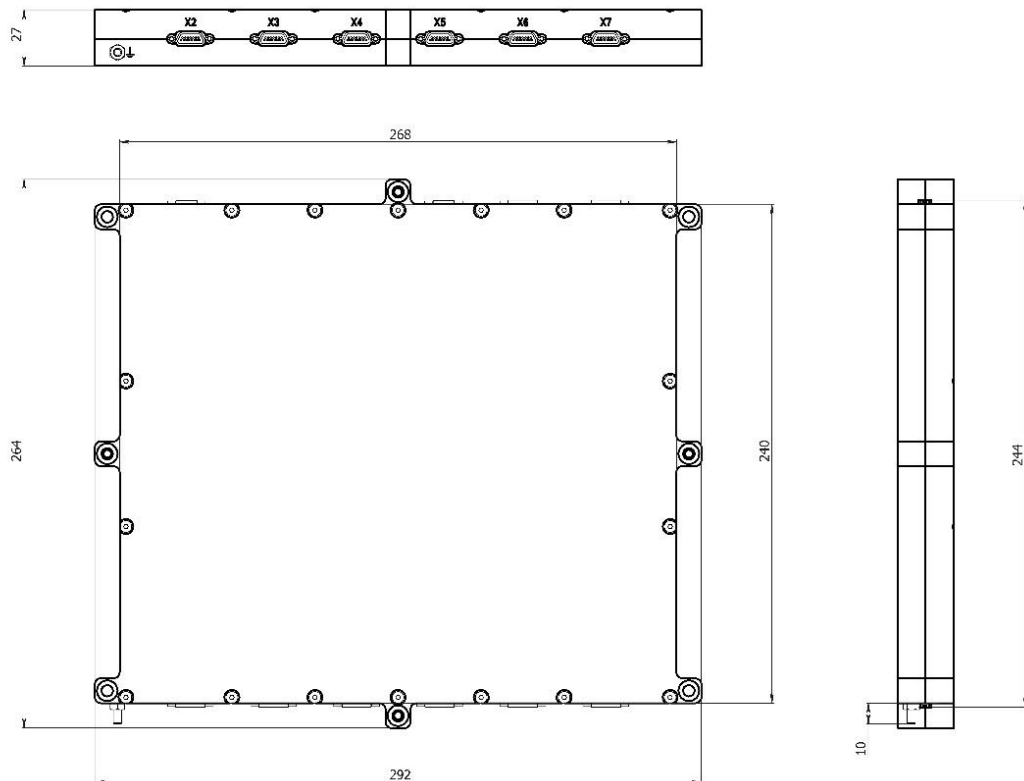
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## Block diagram



## Mechanical outline drawing



## Heritage

The On-board Memory Unit prototype was used with NUCLEON experiment on the Resurs-P satellite (3 years of continuous operation), and on other satellites.